



SCHOTTKY BARRIER RECTIFIER

SS32F-- SS320F

**Reverse Voltage - 20 to 200 V
Forward Current - 3.0A**

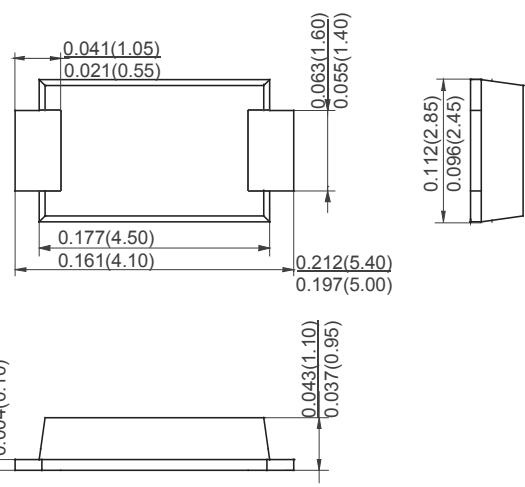
FEATURES

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case: SMAF molded plastic body
- Terminals: Lead solderable per MIL-STD-750, method 2026
- Polarity: Color band denotes cathode end

SMAF



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

| Parameter | Symbols | SS32F | SS34F | SS34AF | SS36F | SS38F | SS310F | SS312F | SS315F | SS320F | Units |
|---------------------------------------------------------------------------------------------------------|--------------------------------------|-------|-------|------------|-------|-------|--------|--------|--------|--------|-------|
| Maximum Repetitive Peak Reverse Voltage | V _{RRM} | 20 | 40 | 45 | 60 | 80 | 100 | 120 | 150 | 200 | V |
| Maximum RMS voltage | V _{RMS} | 14 | 28 | 31.5 | 42 | 56 | 70 | 84 | 105 | 140 | V |
| Maximum DC Blocking Voltage | V _{DC} | 20 | 40 | 45 | 60 | 80 | 100 | 120 | 150 | 200 | V |
| Maximum Average Forward Rectified Current | I _{F(AV)} | | | | | | | 3.0 | | | A |
| Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method) | I _{FSM} | | | 80 | | | | 70 | | | A |
| Max Instantaneous Forward Voltage at 3 A | V _F | 0.55 | | 0.70 | | 0.85 | | 0.95 | | | V |
| Maximum DC Reverse Current T _a = 25°C at Rated DC Reverse Voltage T _a = 100°C | I _R | | 0.5 | | 10 | | 0.3 | | 5 | | mA |
| Typical Junction Capacitance ⁽¹⁾ | C _j | 250 | | 250 | | 160 | | 160 | | | pF |
| Typical Thermal Resistance ⁽²⁾ | R _{θJA} R _{θJC} | | | 40 | | | | | | | °C/W |
| Operating Junction Temperature Range | T _j | | | -55 ~ +125 | | | | | | | °C |
| Storage Temperature Range | T _{stg} | | | -55 ~ +150 | | | | | | | °C |

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C.

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.



RATINGS AND CHARACTERISTIC CURVES

Fig.1 Forward Current Derating Curve

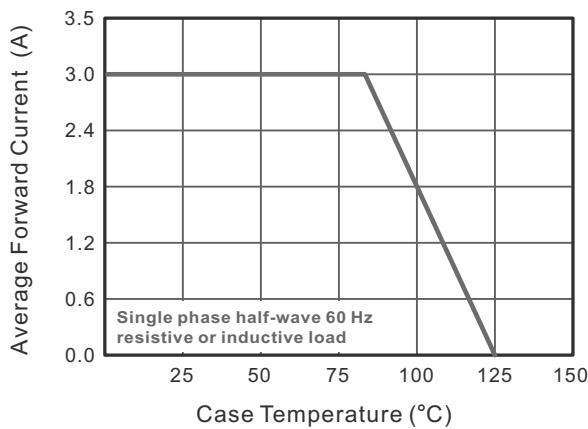


Fig.2 Typical Reverse Characteristics

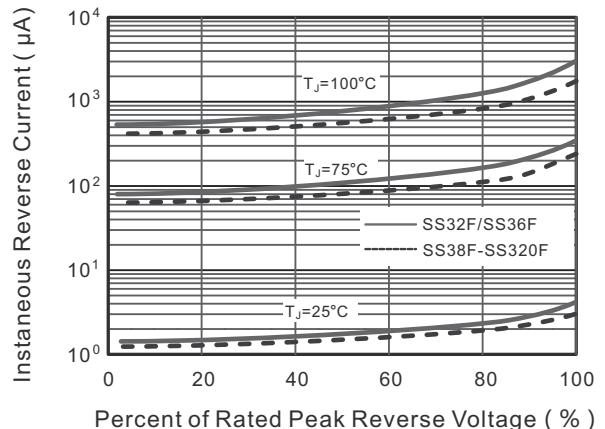


Fig.3 Typical Forward Characteristic

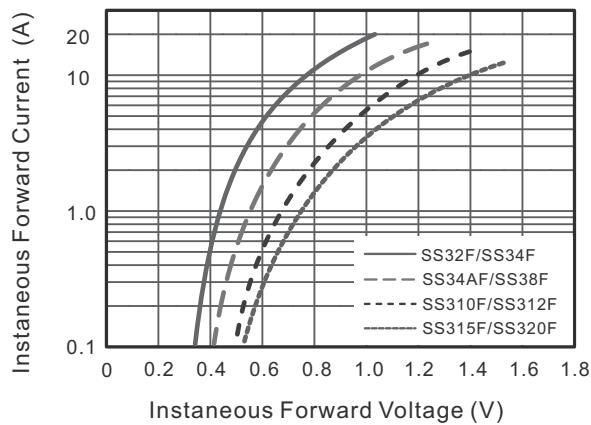


Fig.4 Typical Junction Capacitance

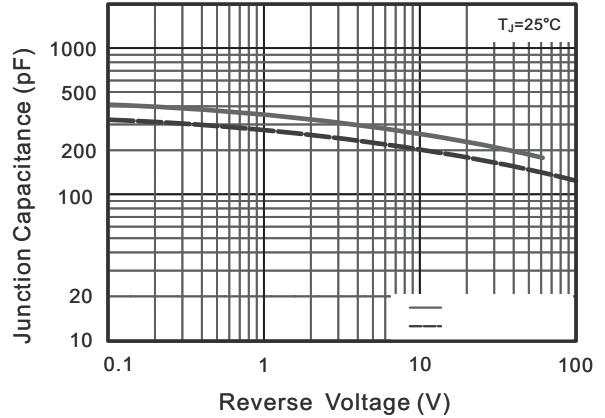


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

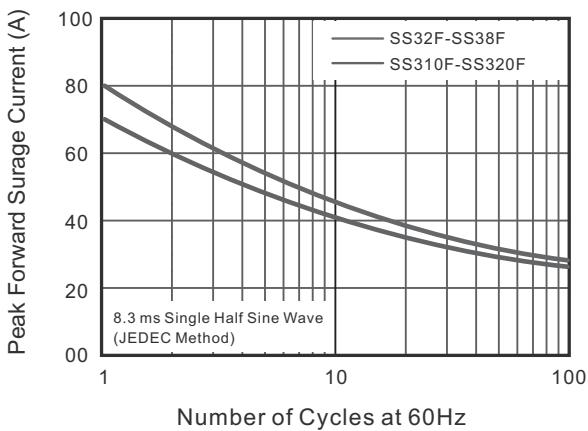


Fig.5- Typical Transient Thermal Impedance

